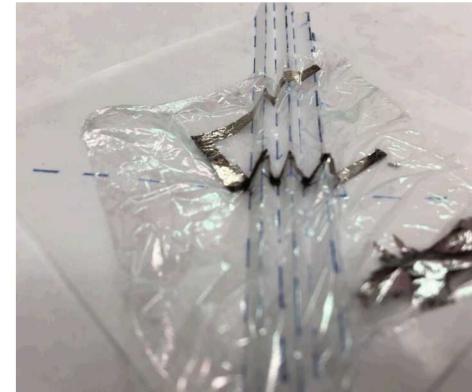
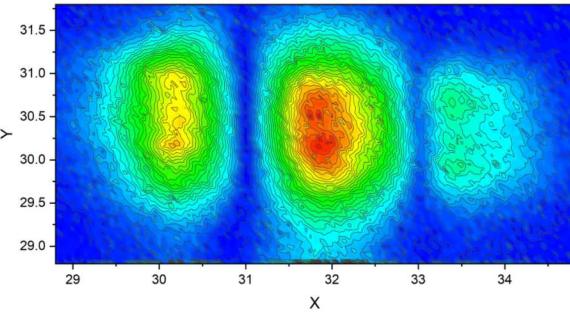


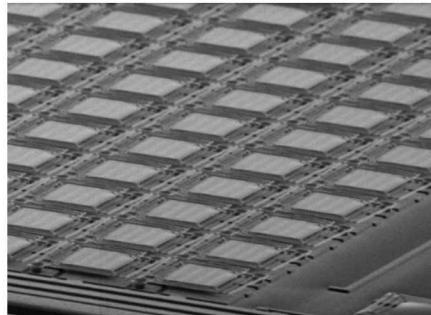
Progress in Carbon Nanotube Terahertz Photodetectors

Juan Pablo Llinas, Michelle Hekmaty, Alec Talin, François Léonard

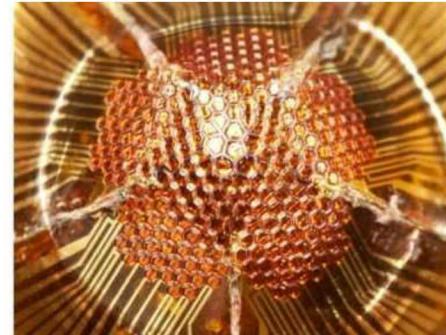
*Sandia National Laboratories
Livermore, CA*



Photodetectors have traditionally been planar:

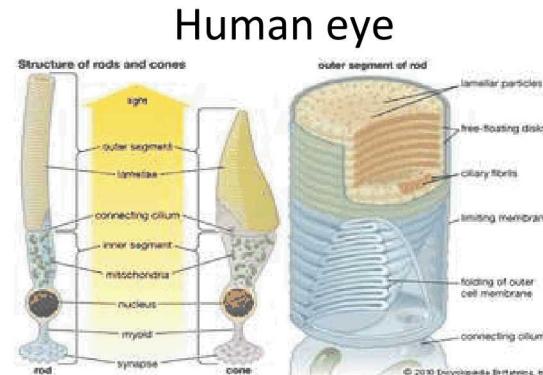


Next step is to consider **curved** detectors:



Zhang et al, Nat. Comm. (2017)

Nature is already a step ahead: 3D detectors

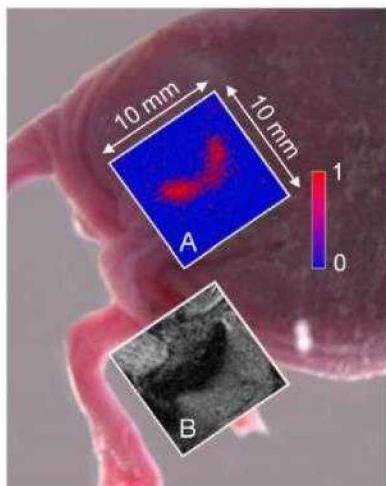


www.britannica.com

➤ The future: complex 3D shapes that are dynamically reconfigurable

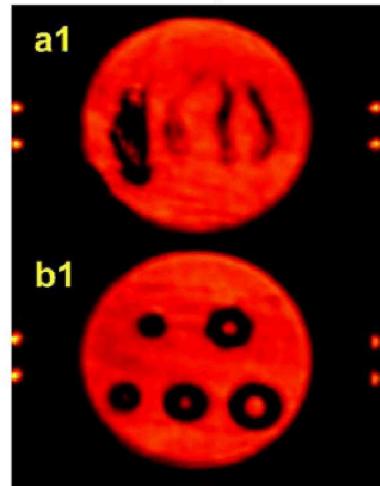
Terahertz is promising for a number of applications:

Medicine



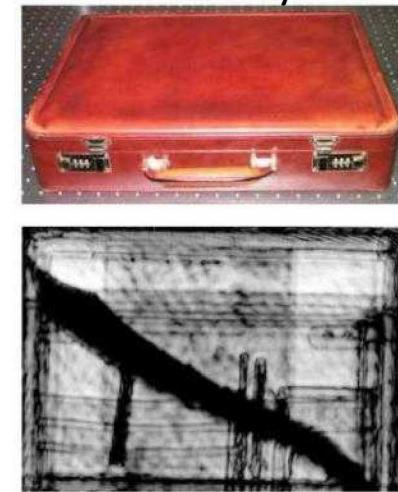
Park et al
IEEE Trans. THz S&T (2012)

Food inspection



Ok et al
Food Control (2014)

Security



Liu et al
Proc. IEEE (2007)

Existing uncooled THz detector technology

Can we make something like this?

Detector type

Golay cell

Piezoelectric

VO_x microbolometer

Bi microbolometer

Nb microbolometer

Ti microbolometer

Ni microbolometer

Schottky diodes

Schottky diode (z)

Mott diodes

Si MOSFET

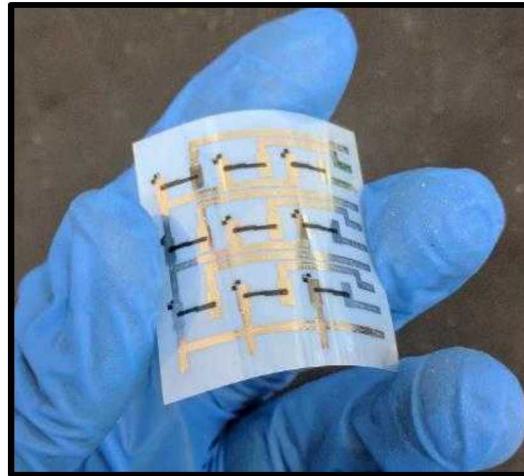
Si FET

Si CMOS

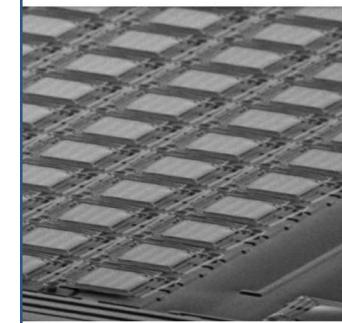
SiN membrane

Micro-Golay cell

HgCdTe HEB



- Non-planar
- Flexible
- Room temperature
- No antenna
- Unpowered



Rigid
Planar
Complex fab
Monolithic
Antenna
Powered

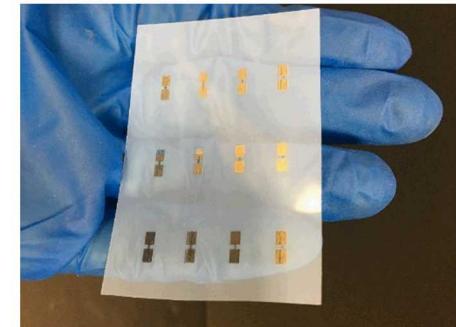
➤ Inkjet printing of nanomaterials

Unique challenges for inkjet printed THz detectors

- Printed active material must absorb as much THz as possible
 - Requires thick films, not typical for inkjet printing of active devices
- Device must generate photocurrent
 - Requires p-type and/or n-type inks
- Inks must be stable and printable
- Substrate compatibility for printing
- Devices must be stable to environment

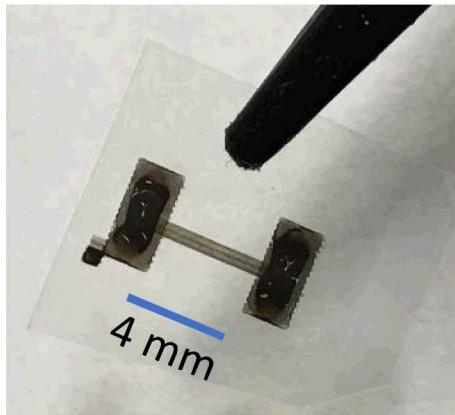


Fuji Dimatix Inkjet Printer



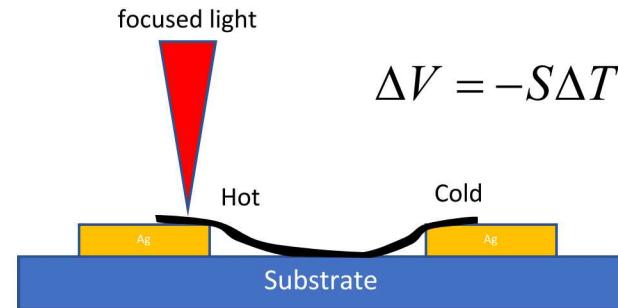
Previously

substrate 110um PET



$$THz\ NEP = \frac{noise}{responsivity} \sim 150\ nW/\sqrt{Hz}$$

Photothermoelectric



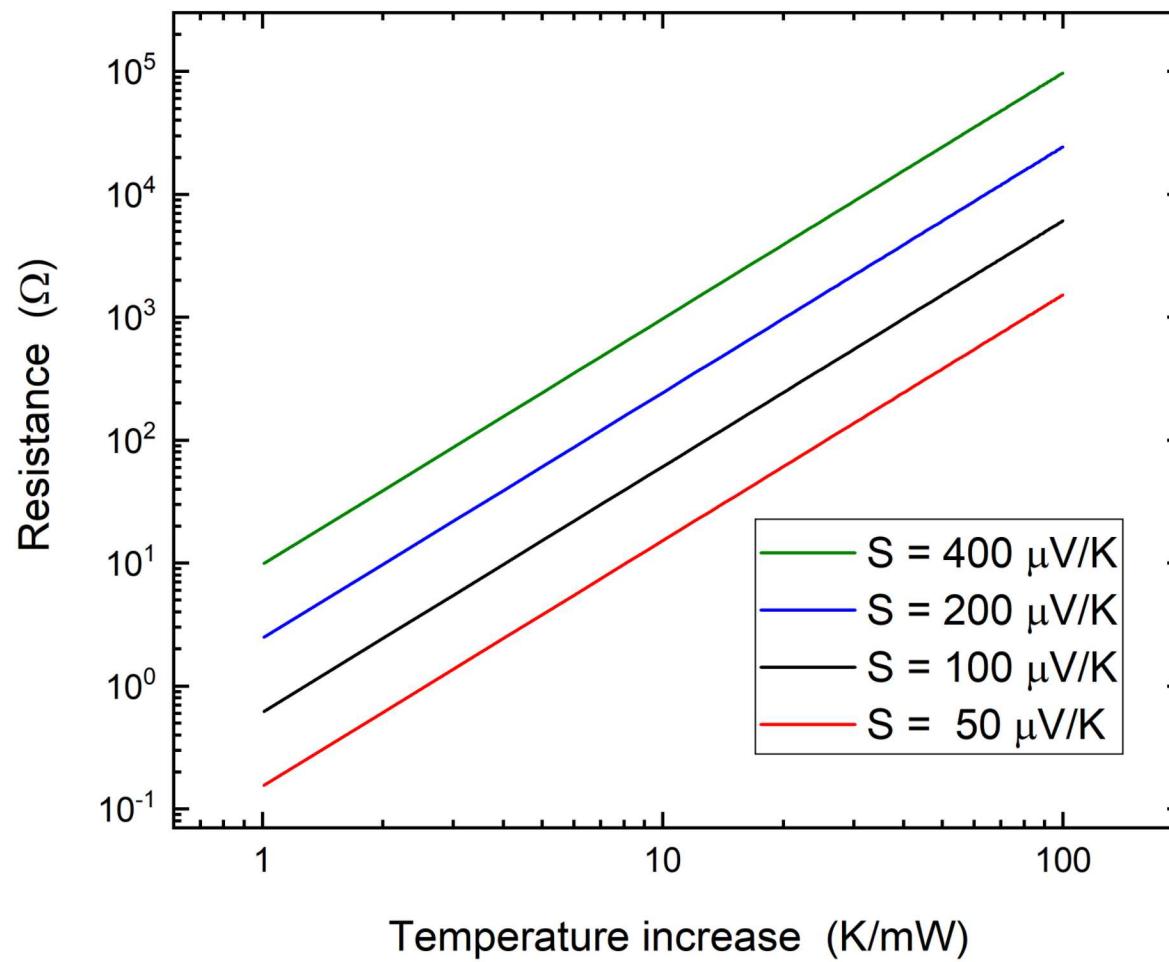
How to improve performance?

- Materials
- Substrate
- Doping
- Geometry

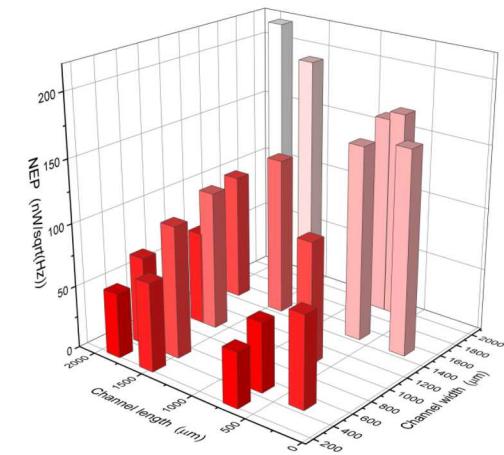
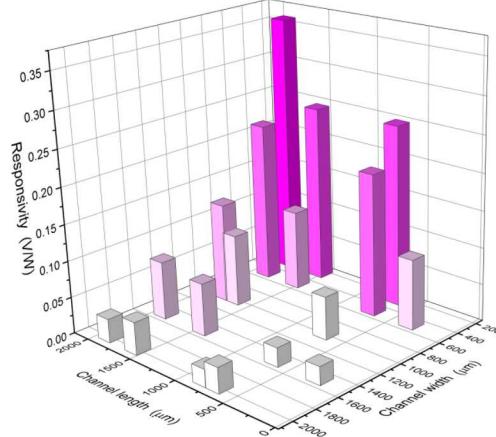
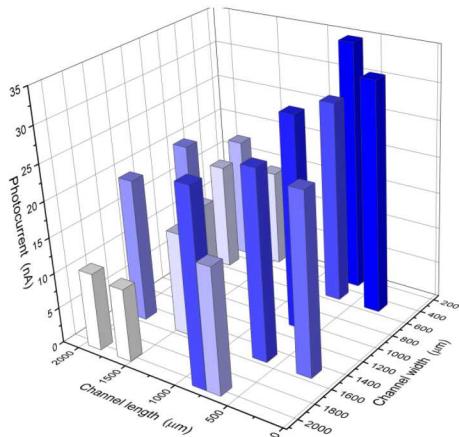
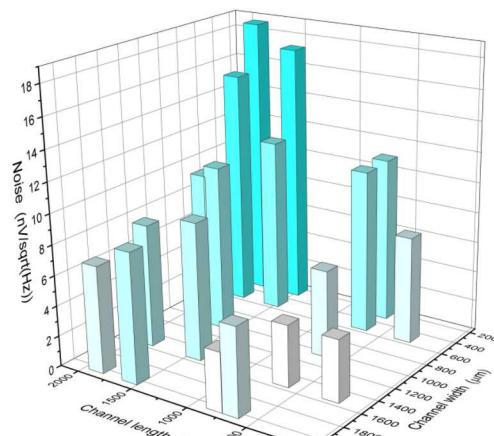
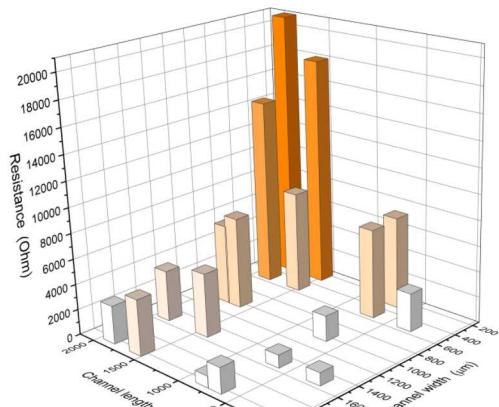
How to get to 3D?

- Ultraflexible
- Architecture

Properties needed to get $1 \text{ nW/Hz}^{1/2}$



Optimizing pixel geometry



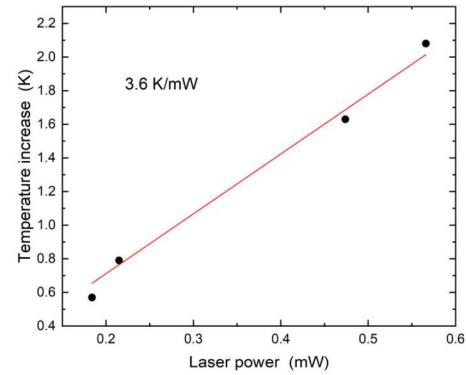
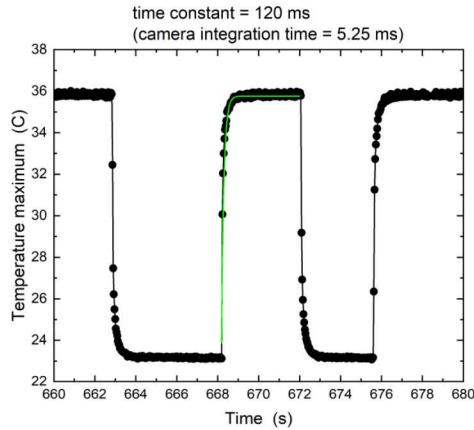
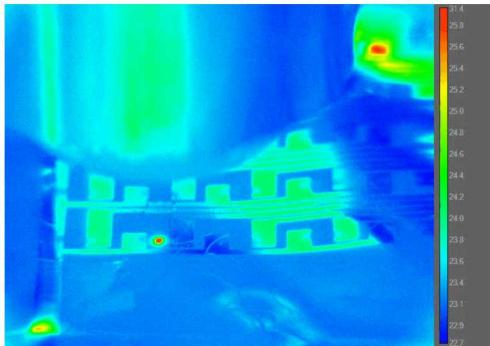
-110 μm PET substrate
-Unwashed semiconducting+metal CNTs

Temperature Increase and Substrate

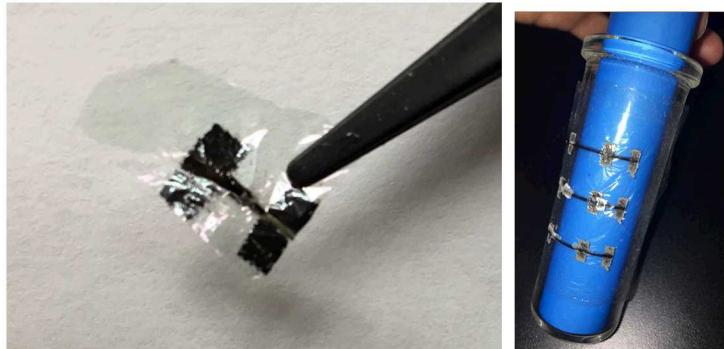
-110 μm PET substrate

-Unwashed semiconducting+metal CNTs

focused green laser



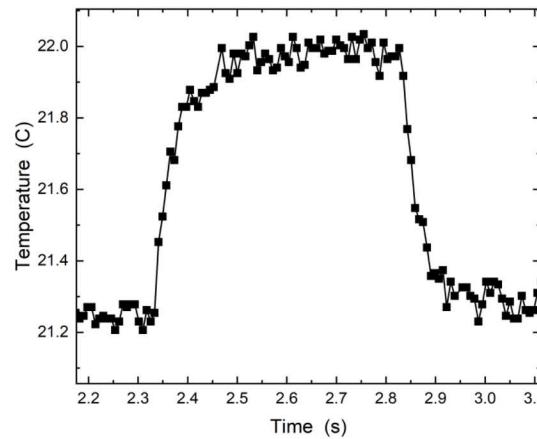
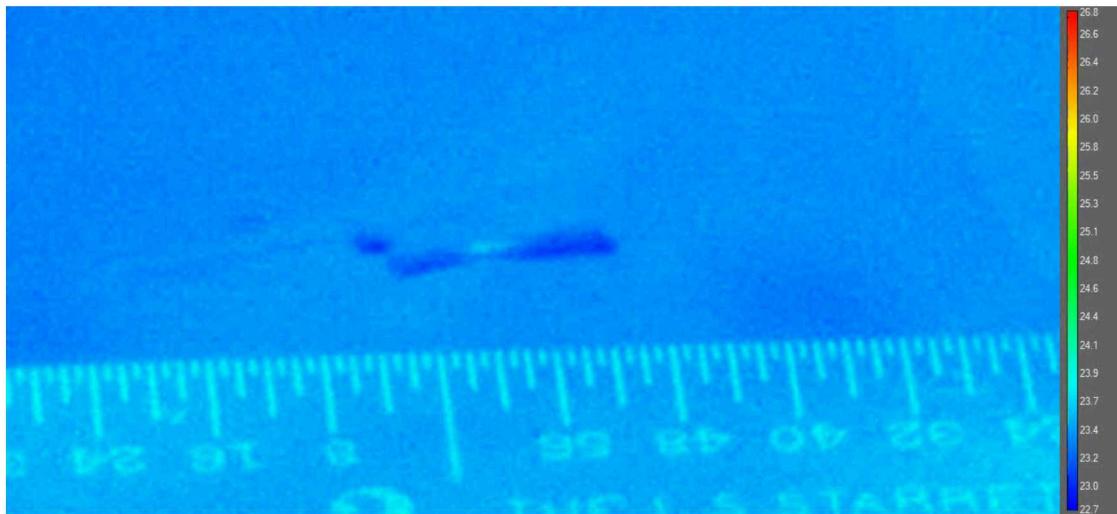
- Small temperature increase and slow
- Solution: ultrathin substrate



Substrate 0.9 μm PET

Up to 17 K/mW!

Observation of heating by THz beam

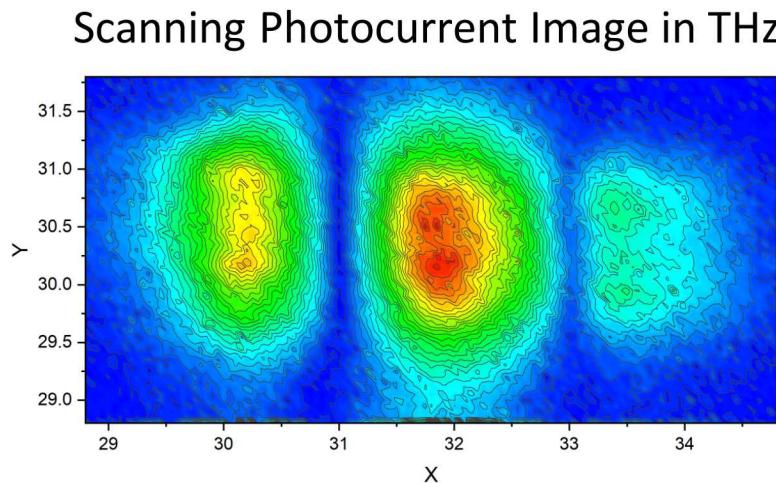
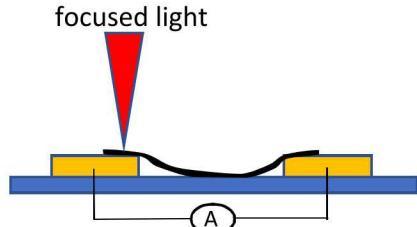


response time = 39 ms

- Larger temperature increase and faster response

Materials and Doping

Semi+metallic CNTs
0.9um PET
PVP doping

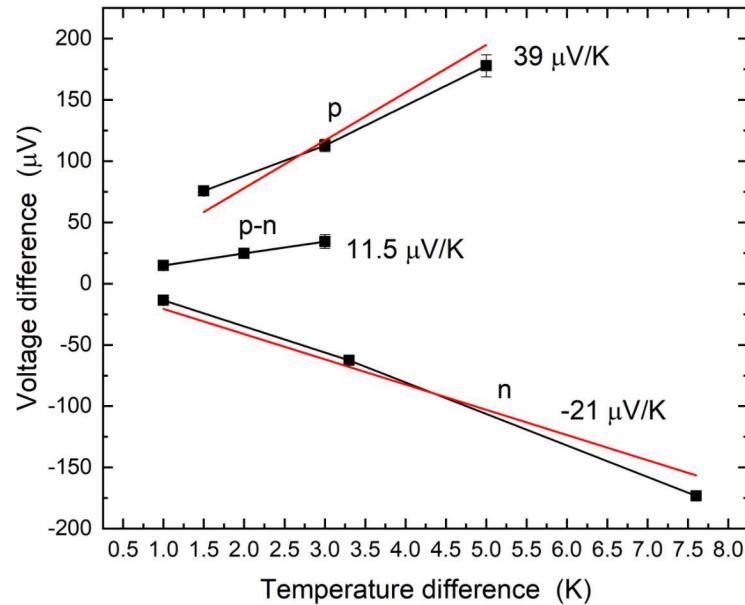


$$THz\ NEP = \frac{noise}{responsivity} \sim 30\ nW/\sqrt{Hz}$$

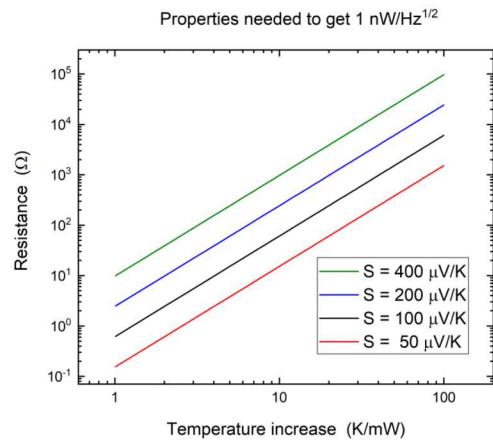
Materials and Doping

Thermoelectric measurements

Semi+metallic CNTs



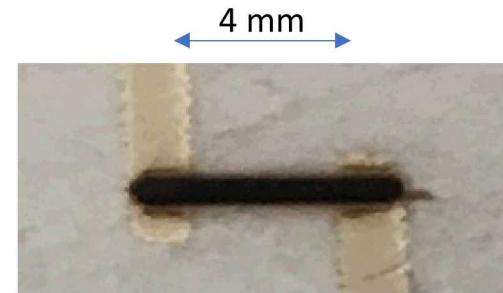
Resistance \sim a few $\text{k}\Omega$ at best



- Seebeck too low
- Resistance too high
- Solutions: semiconducting CNTs and removal of surfactants

Materials and Doping

- Surfactant removal:
 - Problem that we need surfactant for n-type
 - Focus on p-type homojunctions
- Semiconductor-rich CNTs (99% Nanointegris)



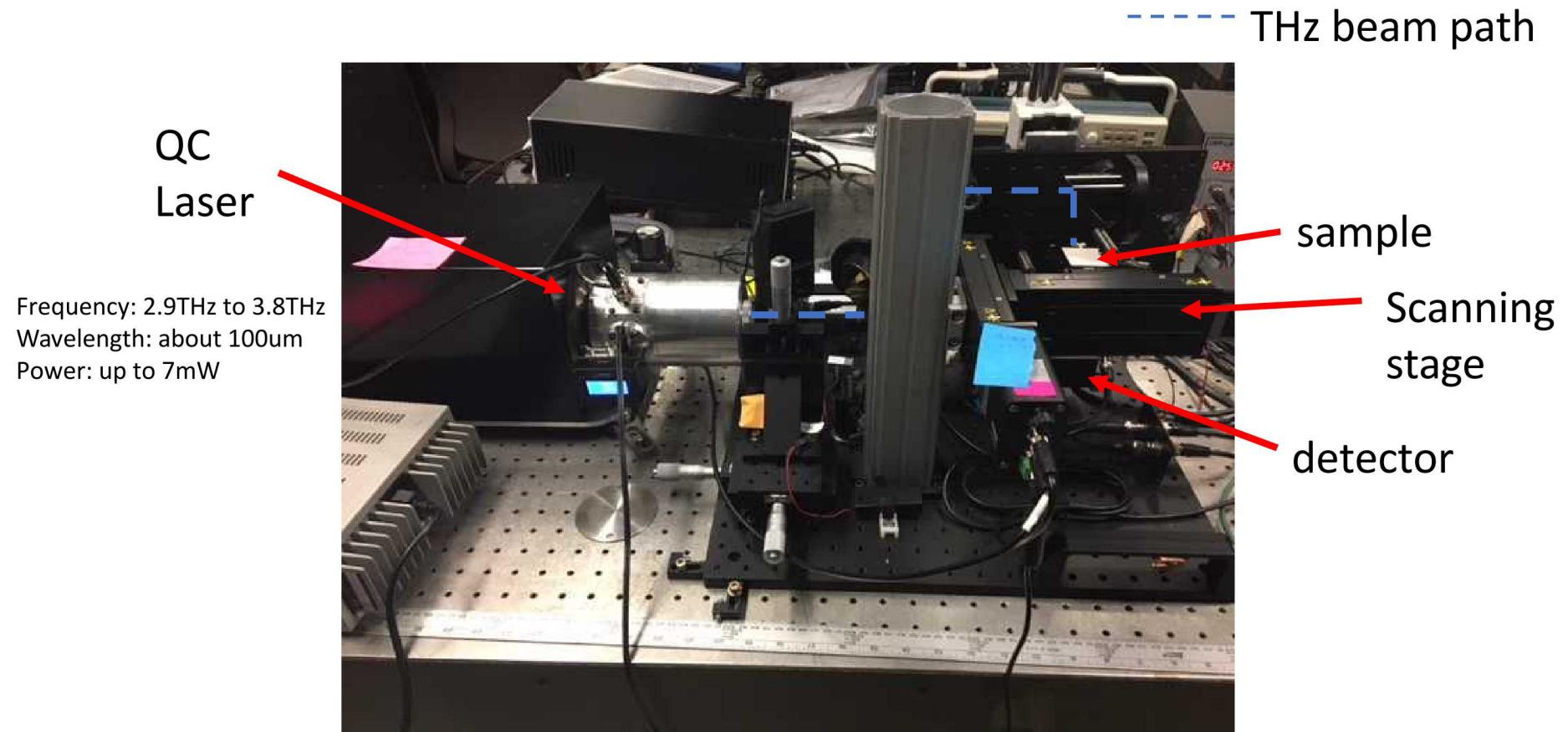
$$\text{Green NEP} = \frac{\text{noise}}{\text{responsivity}} \sim 18 \text{ nW}/\sqrt{\text{Hz}}$$

- Wash devices with DI water

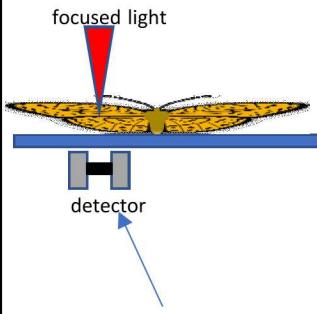
$$\text{Green NEP} = \frac{\text{noise}}{\text{responsivity}} \sim 2 \text{ nW}/\sqrt{\text{Hz}}$$

$$\text{THz NEP} = \frac{\text{noise}}{\text{responsivity}} \sim 25 \text{ nW}/\sqrt{\text{Hz}}$$

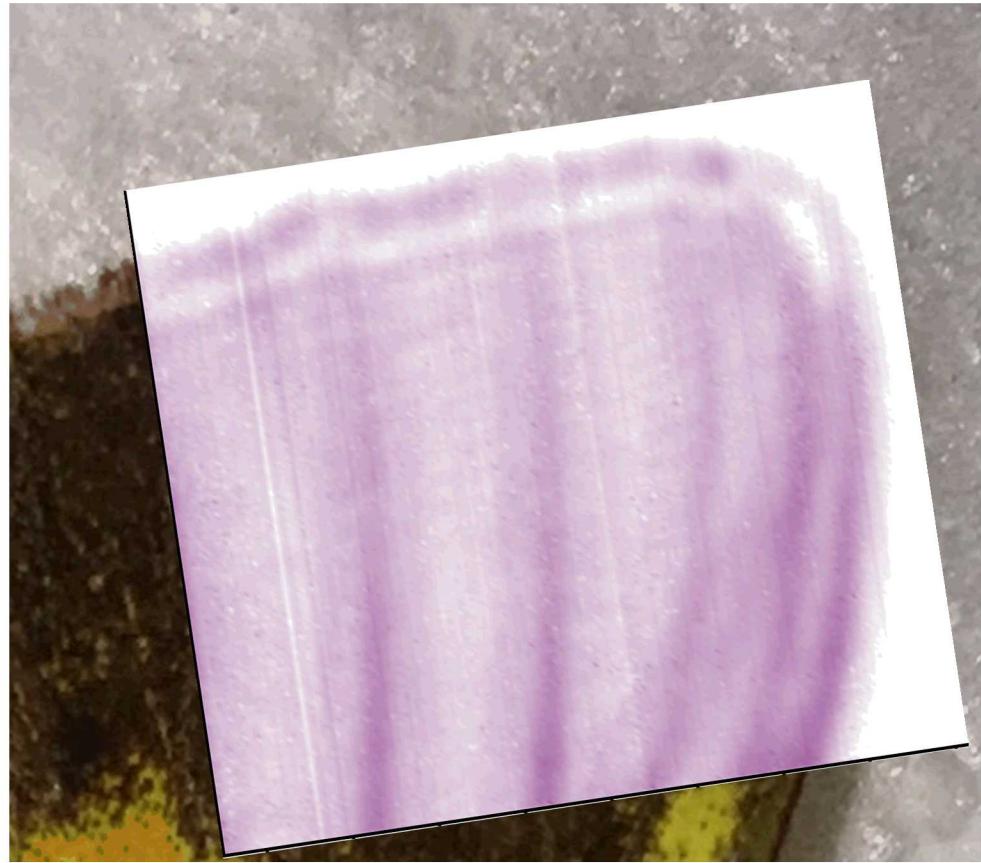
THz imaging



THz imaging using inkjet printed CNT detector

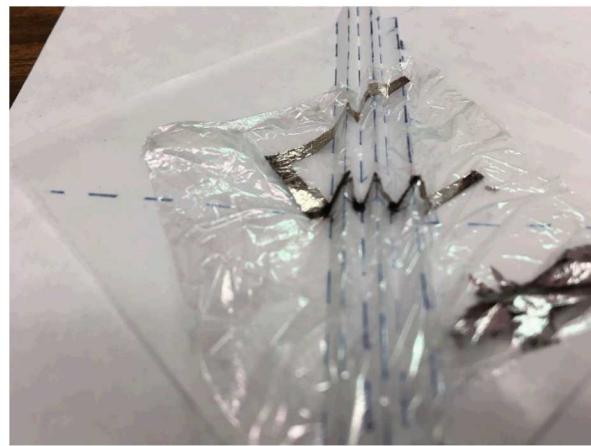


Colias croceus (clouded yellow)



Using our inkjet printed
detector!

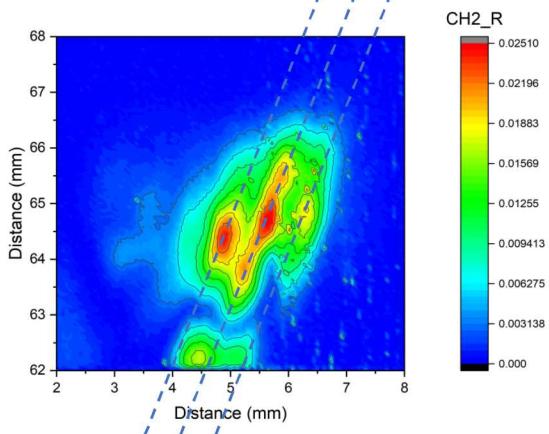
Origami detector



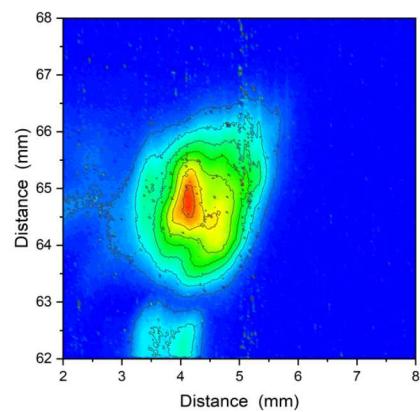
Origami detector



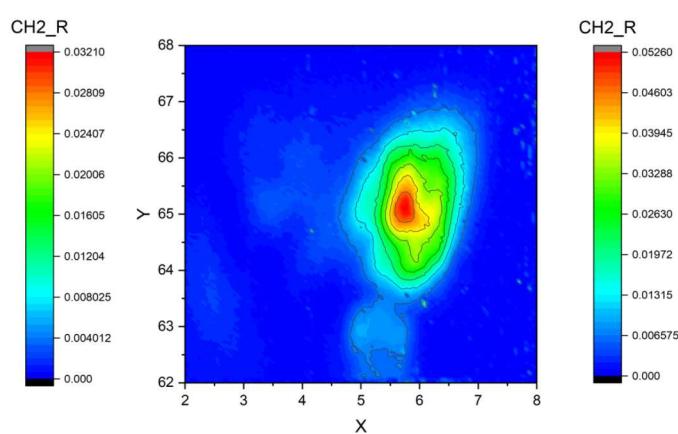
“Loose” folding



“Medium” folding



“Tight” folding



-Three peaks

-Photocurrent amplitude = 0.025

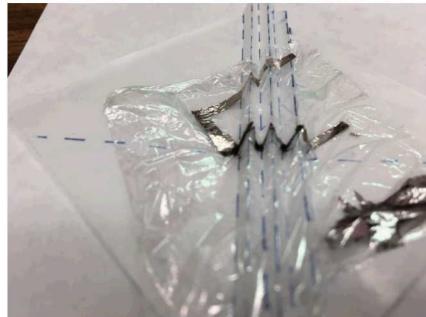
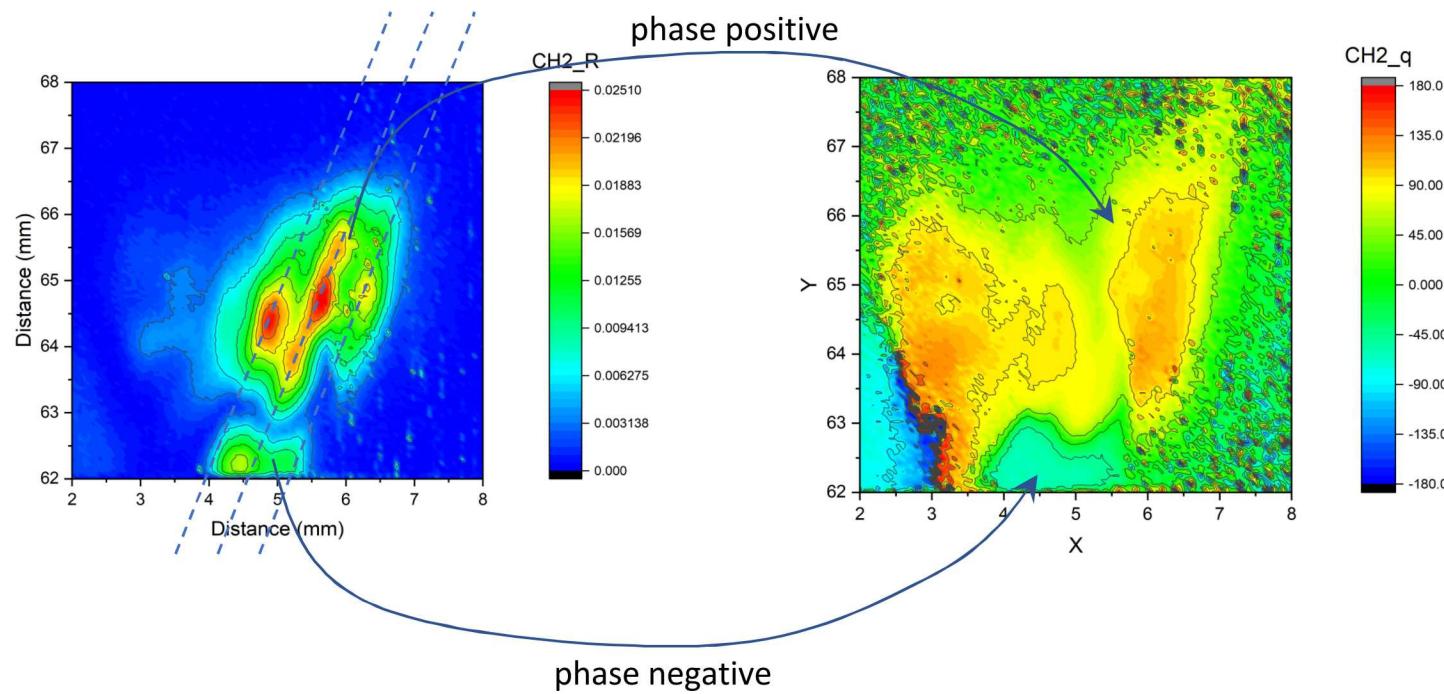
-Two peaks

-Photocurrent amplitude = 0.032

-One peak

-Photocurrent amplitude = 0.052

Origami detector

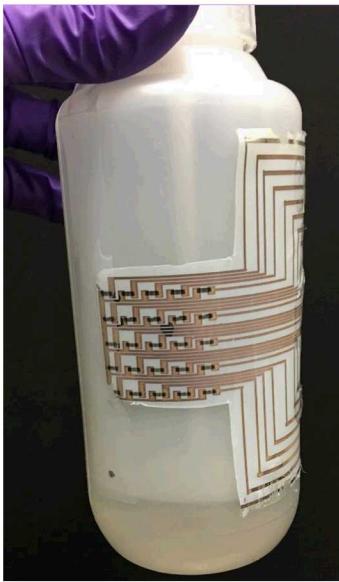


Advantage of origami detector:

The two opposite responses are spatially offset

Future

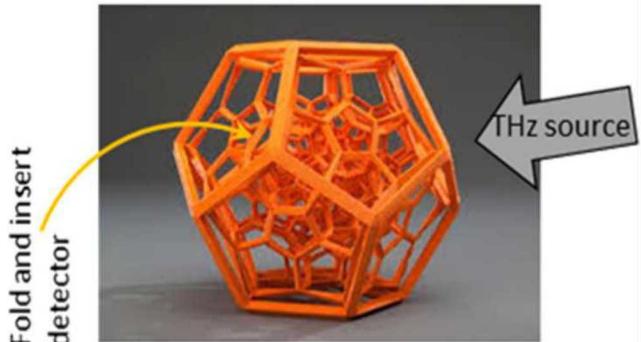
Non-planar, flexible imaging array



Ultraflexible, embedded, state-of-health sensors



Insertable, deployable sensors



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